# Dual Common Base-Collector Bias Resistor Transistors

# NPN and PNP Silicon Surface Mount Transistors with Monolithic Bias Resistor Network

The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. These digital transistors are designed to replace a single device and its external resistor bias network. The BRT eliminates these individual components by integrating them into a single device. The NSTB1005DXV5T1 contains two complementary BRT devices are housed in the SOT-553 package which is ideal for low power surface mount applications where board space is at a premium.

#### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- Available in 8 mm, 7 inch Tape and Reel
- This is a Pb–Free Device

**MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$  unless otherwise noted, common for  $Q_1$  and  $Q_2$ , – minus sign for  $Q_1$  (PNP) omitted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc
Collector-Emitter Voltage	V <sub>CEO</sub>	50	Vdc
Collector Current	Ι <sub>C</sub>	100	mAdc

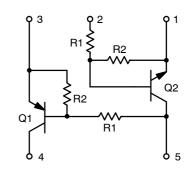
#### THERMAL CHARACTERISTICS

Symbol	Max	Unit
P <sub>D</sub>	357 2.9	mW mW/°C
R <sub>θJA</sub>	350	°C/W
Symbol	Мах	Unit
P <sub>D</sub>	500 4.0	mW mW/°C
R <sub>θJA</sub>	250	°C/W
T <sub>J</sub> , T <sub>stq</sub>	-55 to +150	°C
	P <sub>D</sub> R <sub>θJA</sub> Symbol P <sub>D</sub> R <sub>θJA</sub>	PD 357 2.9 $R_{\theta JA}$ 350   Symbol Max   PD 500 4.0 $R_{\theta JA}$ 250



### **ON Semiconductor®**

http://onsemi.com





#### MARKING DIAGRAM



UC = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

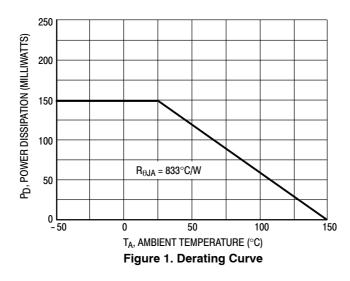
	Device	Package	Shipping <sup>†</sup>
I	NSTB1005DXV5T1G	SOT-553 (Pb-Free)	4000/Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

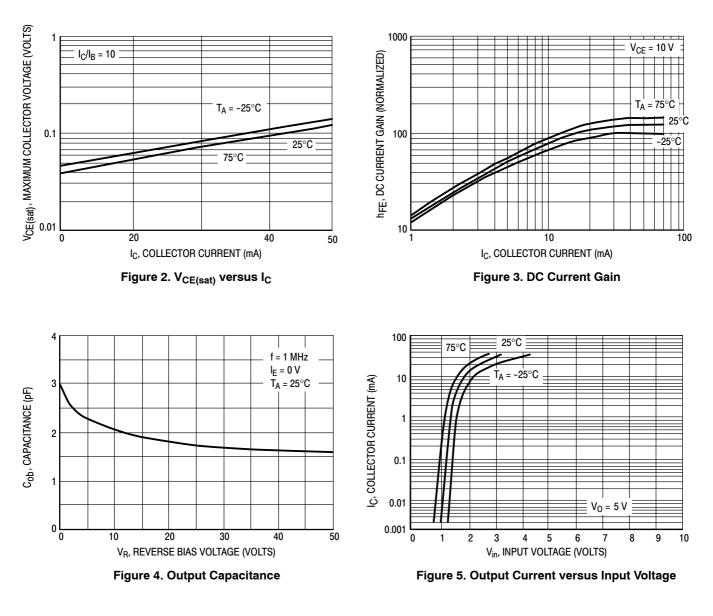
1. FR-4 @ Minimum Pad

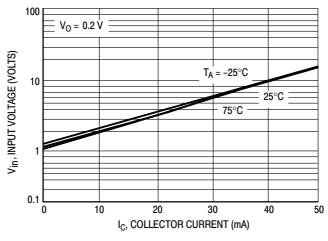
## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

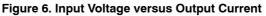
Characteristic	Symbol	Min	Тур	Max	Unit
Q1 TRANSISTOR: PNP – OFF CHARACTERISTICS					
Collector-Base Cutoff Current ( $V_{CB} = 50 \text{ V}, I_E = 0$ )	I <sub>CBO</sub>	-	-	100	nAdc
Collector-Emitter Cutoff Current ( $V_{CE}$ = 50 V, $I_B$ = 0)	I <sub>CEO</sub>	-	-	500	nAdc
Emitter–Base Cutoff Current ( $V_{EB}$ = 6.0 V, $I_C$ = 0)	I <sub>EBO</sub>	-	-	0.1	mAdc
Collector-Base Breakdown Voltage ( $I_C = 10 \ \mu A$ , $I_E = 0$ )	V <sub>(BR)CBO</sub>	50	-	-	Vdc
Collector-Emitter Breakdown Voltage ( $I_C$ = 2.0 mA, $I_B$ = 0)	V <sub>(BR)CEO</sub>	50	-	-	Vdc
ON CHARACTERISTICS					
DC Current Gain	h <sub>FE</sub>	80	140	-	
Collector-Emitter Saturation Voltage ( $I_C = 10 \text{ mA}, I_E = 0.3 \text{ mA}$ )	V <sub>CE(sat)</sub>	-	-	0.25	Vdc
Output Voltage (on) (V_{CC} = 5.0 V, V_B = 3.5 V, R_L = 1.0 k\Omega)	V <sub>OL</sub>	-	-	0.2	Vdc
Output Voltage (off) (V_{CC} = 5.0 V, V_B = 0.5 V, R_L = 1.0 k\Omega)	V <sub>OH</sub>	4.9	-	-	Vdc
Input Resistor	R1	32.9	47	61.1	kΩ
Resistor Ratio	R <sub>1</sub> /R <sub>2</sub>	0.8	1.0	1.2	
Q2 TRANSISTOR: NPN – OFF CHARACTERISTICS					
Collector-Base Cutoff Current (V <sub>CB</sub> = 50 V, $I_E$ = 0)	I <sub>CBO</sub>	-	-	100	nAdc
Collector-Emitter Cutoff Current ( $V_{CB} = 50 \text{ V}, I_B = 0$ )	I <sub>CEO</sub>	-	-	500	nAdc
Emitter-Base Cutoff Current ( $V_{EB} = 6.0$ , $I_C = 0$ )	I <sub>EBO</sub>	-	-	0.1	mAdc
ON CHARACTERISTICS					
Collector-Base Breakdown Voltage ( $I_C = 10 \ \mu A$ , $I_E = 0$ )	V <sub>(BR)CBO</sub>	50	-	-	Vdc
Collector-Emitter Breakdown Voltage ( $I_C = 2.0 \text{ mA}, I_B = 0$ )	V <sub>(BR)CEO</sub>	50	-	-	Vdc
DC Current Gain ( $V_{CE}$ = 10 V, $I_{C}$ = 5.0 mA)	h <sub>FE</sub>	80	140	-	
Collector-Emitter Saturation Voltage ( $I_C$ = 10 mA, $I_B$ = 0.3 mA)	V <sub>CE(SAT)</sub>	-	-	0.25	Vdc
Output Voltage (on) (V_{CC} = 5.0 V, V_B = 2.5 V, R_L = 1.0 k\Omega)	V <sub>OL</sub>	-	-	0.2	Vdc
Output Voltage (off) (V_{CC} = 5.0 V, V_B = 0.5 V, R_L = 1.0 k\Omega)	V <sub>OH</sub>	4.9	-	-	Vdc
Input Resistor	R1	33	47	61	kΩ
Resistor Ratio	R1/R2	0.8	1.0	1.2	



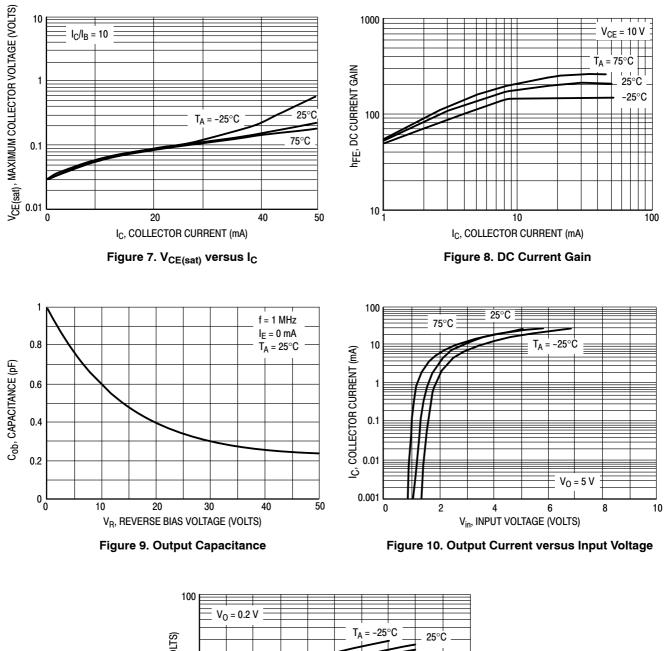
### **TYPICAL ELECTRICAL CHARACTERISTICS – PNP TRANSISTOR**







### **TYPICAL ELECTRICAL CHARACTERISTICS — NPN TRANSISTOR**



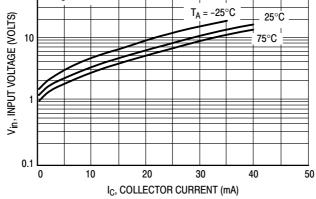
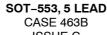


Figure 11. Input Voltage versus Output Current

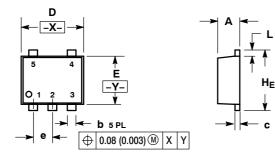




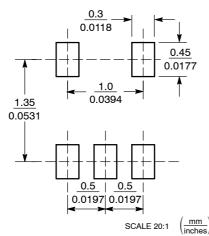
SCALE 4:1



ISSUE C



#### RECOMMENDED **SOLDERING FOOTPRINT\***



NOTES

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2 3.

CONTROLLING DIMENSION: MILLIMETERS MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.50	0.55	0.60	0.020	0.022	0.024
b	0.17	0.22	0.27	0.007	0.009	0.011
С	0.08	0.13	0.18	0.003	0.005	0.007
D	1.55	1.60	1.65	0.061	0.063	0.065
E	1.15	1.20	1.25	0.045	0.047	0.049
е	0.50 BSC			0.020 BSC		
Г	0.10	0.20	0.30	0.004	0.008	0.012
HE	1.55	1.60	1.65	0.061	0.063	0.065

## GENERIC **MARKING DIAGRAM\***

## XXM•

XX = Specific Device Code M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE 1	PIN 1. SOURCE 1	PIN 1. ANODE
2. EMITTER	2. COMMON ANODE	2. N/C	2. DRAIN 1/2	2. EMITTER
3. BASE	3. CATHODE 2	3. ANODE 2	3. SOURCE 1	3. BASE
4. COLLECTOR	4. CATHODE 3	4. CATHODE 2	4. GATE 1	4. COLLECTOR
5. COLLECTOR	5. CATHODE 4	5. CATHODE 1	5. GATE 2	5. CATHODE
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	
PIN 1. EMITTER 2	PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE	
2. BASE 2	2. EMITTER	2. COLLECTOR	2. CATHODE	
3. EMITTER 1	3. BASE	3. N/C	3. ANODE	
4. COLLECTOR 1	4. COLLECTOR	4. BASE	4. ANODE	
5. COLLECTOR 2/BASE 1	5. COLLECTOR	5. EMITTER	5. ANODE	

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### DOCUMENT NUMBER: 98AON11127D

PAGE 2 OF 2

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Α	ADDED STYLES 3–9. REQ. BY D. BARLOW	11 NOV 2003			
В	ADDED NOMINAL VALUES AND UPDATED GENERIC MARKING DIAGRAM. REQ. BY HONG XIAO	27 MAY 2005			
С	UPDATED DIMENSIONS D, E, AND HE. REQ. BY J. LETTERMAN.	20 MAR 2013			

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